DISCRETE SEMICONDUCTORS



Product specification File under Discrete Semiconductors, SC07 December 1997



PN4416; PN4416A

FEATURES

- Low noise
- Interchangeability of drain and source connections
- High gain.

DESCRIPTION

N-channel symmetrical silicon junction FETs in a SOT54 envelope. These devices are intended for use in VHF/UHF amplifiers, oscillators and mixers.

PINNING - SOT54 (TO-92).

PIN	DESCRIPTION
1	gate
2	source
3	drain

QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage				
	PN4416		_	30	V
	PN4416A		_	35	V
I _{DSS}	drain current	V _{DS} = 15 V; V _{GS} = 0	5	15	mA
P _{tot}	total power dissipation	up to T _{amb} = 25 °C	_	400	mW
V _{GS(off)}	gate-source cut-off voltage	V _{DS} = 15 V; I _D = 1 nA			
	PN4416		_	-6	V
	PN4416A		-2.5	-6	V
Y _{fs}	common-source transfer admittance	V _{DS} = 15 V; V _{GS} = 0; f = 1 kHz	4.5	7.5	mS



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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	drain-source voltage				
	PN4416		_	30	V
	PN4416A		_	35	V
V _{GSO}	gate-source voltage				
	PN4416		_	-30	V
	PN4416A		-	-35	V
V _{GDO}	gate-drain voltage				
	PN4416		_	-30	V
	PN4416A		_	-35	V
I _G	DC forward gate current		_	10	mA
P _{tot}	total power dissipation	up to $T_{amb} = 25 \ ^{\circ}C$ (note 1)	_	400	mW
T _{stg}	storage temperature		-65	+150	°C
Т _ј	junction temperature		-	150	°C

THERMAL RESISTANCE

SYMBOL	PARAMETER	THERMAL RESISTANCE
R _{th j-a}	from junction to ambient (note 1)	350 K/W

Note

1. Mounted on a printed-circuit board, maximum lead length 4 mm, mounting pad for drain leads 10 mm².

STATIC CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{(BR)GSS}	gate-source breakdown voltage	$V_{DS} = 0; I_G = -1 \ \mu A$			
	PN4416		-30	-	V
	PN4416A		-35	-	V
I _{GSS}	reverse gate leakage current	V _{DS} = 0; V _{GS} = -15 V	-	-1	nA
I _{DSS}	drain current	$V_{DS} = 15 \text{ V}; V_{GS} = 0$	5	15	mA
V _{GSS}	gate-source forward voltage	V _{DS} = 0; I _G = 1 mA	-	1	V
V _{GS(off)}	gate-source cut-off voltage	V _{DS} = 15 V; I _D = 1 nA			
	PN4416		-	-6	V
	PN4416A		-2.5	-6	V
Y _{fs}	common source transfer admittance	V _{DS} = 15 V; V _{GS} = 0	4.5	7.5	mS
Y _{os}	common source output admittance	V _{DS} = 15 V; V _{GS} = 0			
	PN4416		-	50	μS
	PN4416A		-	50	μS

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DYNAMIC CHARACTERISTICS

 $T_j = 25 \ ^\circ C; \ V_{DS} = 15 \ V; \ V_{GS} = 0. \label{eq:table_eq}$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
C _{is}	input capacitance	f = 1 MHz	-	-	4	pF
C _{os}	output capacitance	f = 1 MHz	-	-	2	pF
C _{rs}	feedback capacitance	f = 1 MHz	-	-	0.8	pF
g _{is}	common source input conductance	f = 100 MHz	-	-	100	μS
		f = 400 MHz	-	-	1	mS
g _{fs}	common source transfer conductance	f = 100 MHz	-	5.2	-	mS
		f = 400 MHz	4	5	-	mS
g _{rs}	common source feedback conductance	f = 100 MHz	-	-8	-	μS
		f = 400 MHz	-	-100	-	μS
g _{os}	common source output conductance	f = 100 MHz	-	-	75	μS
		f = 400 MHz	-	-	100	μS
V _n	equivalent input noise voltage	f = 100 Hz	_	5	-	nV/√Hz





Fig.3 Common source transfer admittance as a function of gate-source cut-off voltage; typical values.

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Fig.13 Common source feedback conductance; typical values.

SPICE parameters for PN4416

September 1992; version 1.0.

•••p		
1	VTO = -3.553	V
2	BETA = 792.6	μA/V ²
3	LAMBDA = 18.46	m/V
4	RD = 7.671	Ω
5	RS = 7.671	Ω
6	IS = 333.4	aA
7	CGSO = 2.920	pF
8	CGDO = 2.261	pF
9	PB = 1.090	V
10 (note 1)	FC = 500.0	m

Note

1. Parameter not extracted; default value.

PACKAGE OUTLINE



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DEFINITIONS

Data sheet status		
Objective specification	This data sheet contains target or goal specifications for product development.	
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.	
Product specification	This data sheet contains final product specifications.	
Short-form specification	The data in this specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.	
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Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

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